NSN 5961-01-479-1979

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-479-1979 **Inclosure Material:** Glass **Overall Length:** Between 0.165 inches and 0.195 inches **End Application:** Kg-20 (crypto) **Mounting Method:** Compression Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc **Special Features:** Unleaded or surface mounte (square end cap diode) **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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